

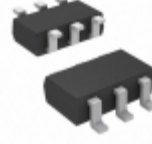

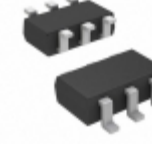




	<p>SI3588DV-T1-E3</p>
	<p>Hersteller-Teilenummer: SI3588DV-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N/P-CH 20V 2.5A 6TSOP</p> <p>Datenblätter:  SI3588DV-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3588DV-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N/P-CH 20V 2.5A 6TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3500 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	830mW, 83mW
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Typ FET	N and P-Channel
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.5A, 570mA
Rds On (Max) @ Id, Vgs	80 mOhm @ 3A, 4.5V
VGS (th) (Max) @ Id	450mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	7.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI3588DV-T1-E3 ist neu im Original, Suche SI3588DV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3588DV-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3588DV-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3586DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.9A 6-TSOP</p>	 <p>SI3590DV-T1-E3 Vishay / Siliconix MOSFET N/P-CH 30V 2.5A 6TSOP</p>	 <p>SI3590DV Vishay Precision Group SI3590DV Vishay</p>	 <p>SI3586DV-T1-E3 Vishay / Siliconix MOSFET N/P-CH 20V 2.9A 6TSOP</p>
 <p>SI3588DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.5A 6TSOP</p>	 <p>SI3588DV VISHAY SI3588DV VISHAY</p>	 <p>SI3588DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.5A 6-TSOP</p>	 <p>SI3586DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.9A 6TSOP</p>

heiße Teile

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|--|---|---|---|--|
|  SI3529DV-T1-GE3 |  SI3529DV-T1-GE3 |  SI3552DV |  SI3552DV-T1 |  SI3552DV-T1-E3 |
|  SI3552DV-T1-E3 |  SI3552DV-T1-GE3 |  SI3552DV-T1-GE3 |  SI3585CDV |  SI3585CDV-T1-GE3 |
|  SI3585CDV-T1-GE3 |  SI3585DV |  SI3585DV-T1 |  SI3585DV-T1-E3 |  SI3585DV-T1-E3 |
|  SI3585DV-T1-GE3 |  SI3585DV-T1-GE3 |  SI3586DS-T1-E3 |  SI3586DV |  SI3586DV-T1-E3 |
|  SI3586DV-T1-E3 |  SI3586DV-T1-GE3 |  SI3586DV-T1-GE3 |  SI3588DV |  SI3588DV-T1-E3 |
|  SI3588DV-T1-GE3 |  SI3588DV-T1-GE3 |  SI3590DV-T1-GE3 |  SI3590DV-T1-GE3 |  SI3801DV-T1 |
|  SI3803DV-T1 |  SI3805DV-T1 |  SI3805DV-T1-E3 |  SI3805DV-T1-E3 |  SI3812DV-T1-GE3 |
|  SI3812DV-T1-GE3 |  SI3850ADV-T1-E3 |  SI3850ADV-T1-E3 |  SI3850ADV-T1-GE3 |  SI3850ADV-T1-GE3 |
|  SI3850DV-T1 |  SI3850DV-T1-E3 |  SI3850DV-T1-GE3 |  SI3851DV |  SI3851DV-T1 |
|  SI3851DV-T1-E3 |  SI3851DV-T1-E3 |  SI3851DV-T1-GE3 |  SI3853DV-T1-E3 |  SI3853DV-T1-E3 |

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